COMPLIANT

HALOGEN

FREE

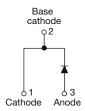


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Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt®





| PRIMARY CHARACTERISTICS | | | | | | | | |
|----------------------------------|-------------|--|--|--|--|--|--|--|
| I _{F(AV)} | 15 A | | | | | | | |
| V _R | 600 V | | | | | | | |
| V _F at I _F | 1.5 V | | | | | | | |
| t _{rr} typ. | 18 ns | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Package | TO-220AC 2L | | | | | | | |
| Circuit configuration | Single | | | | | | | |

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Benchmark ultralow forward voltage drop
- Low leakage current
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 600 | V | | | | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 133 °C | 15 | | | | | | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 170 | Α | | | | | | |
| Peak repetitive forward current | I _{FM} | | 30 | | | | | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | | | | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | | |
|--|-------------------------------------|--|------|------|------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 600 | - | - | V | | | | |
| Forward voltage | M | I _F = 15 A | - | 2.3 | 3.2 | V | | | | |
| | V _F | I _F = 15 A, T _J = 150 °C | - | 1.5 | 1.8 | | | | | |
| Poverse leakage current | | $V_R = V_R$ rated | - | 0.1 | 50 | | | | | |
| Reverse leakage current | I _R | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | 40 | 300 | μA | | | | |
| Junction capacitance | C _T | V _R = 600 V | - | 20 | - | pF | | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nΗ | | | | |

Revision: 11-Jan-2022 1 Document Number: 96176



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| DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified) | | | | | | | | | | |
|---|------------------|-------------------------------------|---|------|------|------|--------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Reverse recovery time | | $I_F = 1 A, dI_F/dt = 100$ | - | 18 | 22 | | | | | |
| | + | $I_F = 15 \text{ A}, dI_F/dt = 100$ | - | 20 | 32 | ne | | | | |
| | t _{rr} | T _J = 25 °C | | - | 22 | - | ns | | | |
| | | T _J = 125 °C | 1. 45 4 | - | 52 | - | | | | |
| Dealessan | I _{RRM} | T _J = 25 °C | I _F = 15 A dI _F /dt = 200 A/μs | - | 2.4 | - | A C | | | |
| Peak recovery current | | T _J = 125 °C | $V_{\rm B} = 390 \text{ V}$ | - | 5.1 | - | | | | |
| Reverse recovery charge | Q _{rr} | T _J = 25 °C | - VR - 000 V | - | 25 | - | | | | |
| neverse recovery charge | | T _J = 125 °C | | - | 150 | - | | | | |
| Reverse recovery time | t _{rr} | | I _F = 15 A | - | 37 | - | ns | | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | $dI_F/dt = 800 A/\mu s$ | - | 16 | - | Α | | | |
| Reverse recovery charge | Q _{rr} | | V _R = 390 V | - | 350 | - | nC | | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|-----------------------------------|---|--------------|------|------------|------------------------|--|--|--|
| PARAMETER | SYMBOL | MBOL TEST CONDITIONS | | TYP. | MAX. | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | |
| Thermal resistance, junction-to-case | R_{thJC} | | ı | 1.0 | 1.3 | | | | |
| Thermal resistance, junction-to-ambient per leg | R _{thJA} | Typical socket mount | - | - | 70 | °C/W | | | |
| Thermal resistance, case-to-heatsink | R _{thCS} | Mounting surface, flat, smooth, and greased | - | 0.5 | - | | | | |
| Weight | | | - | 2.0 | - | g | | | |
| vveignt | | | - | 0.07 | - | oz. | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | |
| Marking device | | Case style TO-220AC 2L | 15ETX06 | | | | | | |

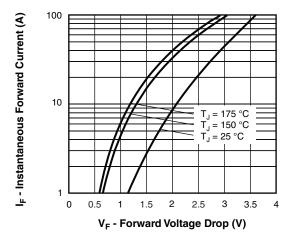


Fig. 1 - Typical Forward Voltage Drop Characteristics

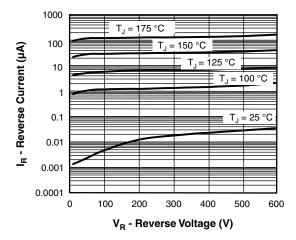


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Revision: 11-Jan-2022 2 Document Number: 96176

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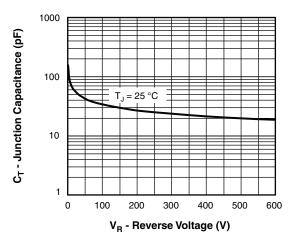


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

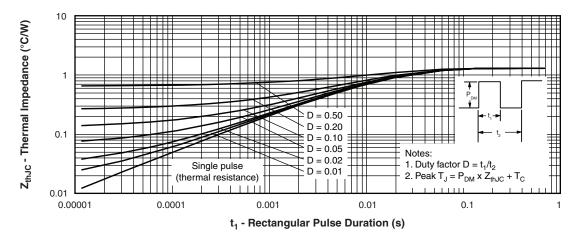


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

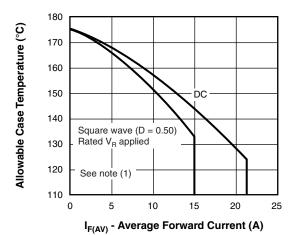


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

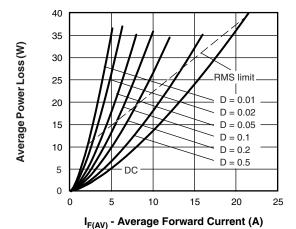


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{thJC}}; \\ \text{Pd} = \text{forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/\text{D}) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = \text{inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = \text{rated V}_{\text{R}} \\ \end{array}$

Revision: 11-Jan-2022 3 Document Number: 96176



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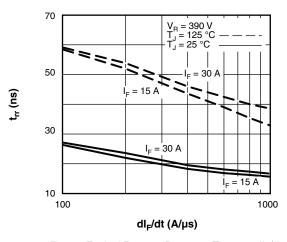


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

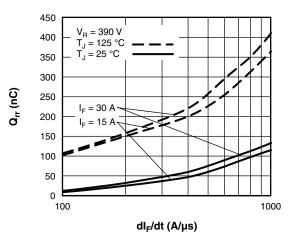
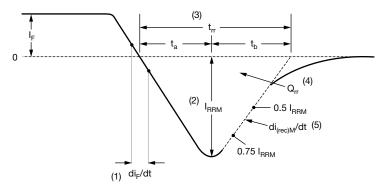


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

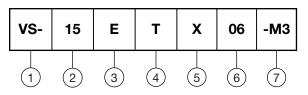
Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (15 = 15 A)

- E = single

- T = TO-220, D²PAK (TO-263AB)

5 - X = hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

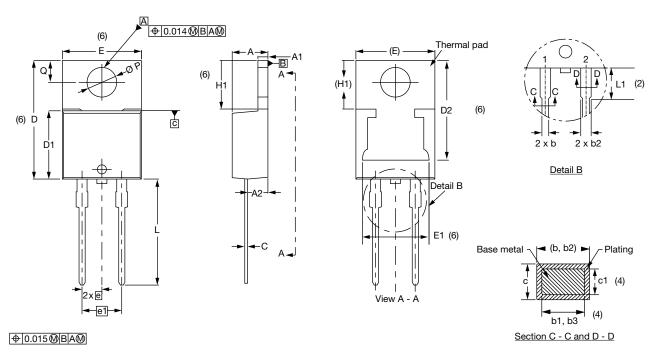
| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|---------------|--------------------------|--|--|--|--|--|--|
| PREFERRED P/N | BASE QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-15ETX06-M3 | 50 | Antistatic plastic tubes | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|--|--|
| Dimensions www.vishay.com/doc?96156 | | | | | | | |
| Part marking information | www.vishay.com/doc?95391 | | | | | | |

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TO-220AC 2L

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC® outline TO-220AC

| SYMBOL | MILLIN | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|--------|--------|-------------|-------|--------|-------|----------|---------|-------------|-------|--------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | ' | STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | | | D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | | E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | | е | 2.41 | 2.67 | 0.095 | 0.105 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | | H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | | ØΡ | 3.54 | 3.91 | 0.139 | 0.154 | |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 | | Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | | | | | | • | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- $^{(7)}\,$ Outline conforms to JEDEC® TO-220, except D2

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